



CPH5611

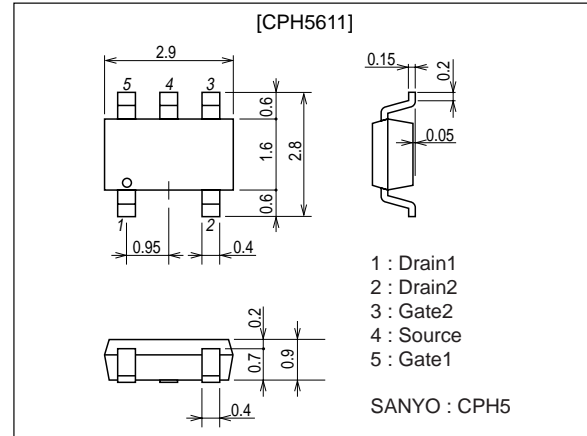
Ultrahigh-Speed Switching Applications

Features

- Low ON-resistance.
- Ultrahigh-speed switching.
- 2.5V drive.
- Composite type with 2 MOSFETs contained in a single package, facilitating high-density mounting.

Package Dimensions

unit : mm
2168



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		20	V
Gate-to-Source Voltage	V _{GSS}		±10	V
Drain Current (DC)	I _D		3	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	12	A
Allowable Power Dissipation	P _D	Mounted on a ceramic board (600mm ² ×0.8mm)1unit	0.9	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	I _D =1mA, V _{GS} =0	20			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0			1	μA
Gate-to-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	y _{fs}	V _{DS} =10V, I _D =1.5A	3.4	4.8		S
Static Drain-to-Source On-State Resistance	R _{DS(on)1}	I _D =1.5A, V _{GS} =4V		54	70	mΩ
	R _{DS(on)2}	I _D =0.7A, V _{GS} =2.5V		73	102	mΩ

Marking : FR

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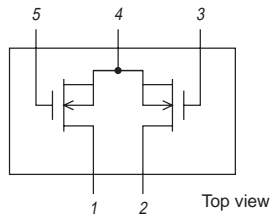
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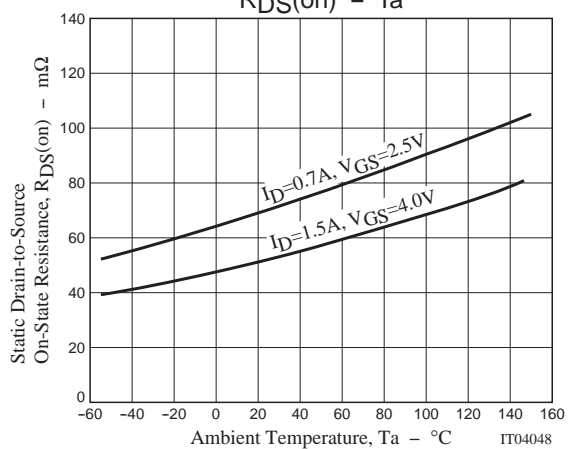
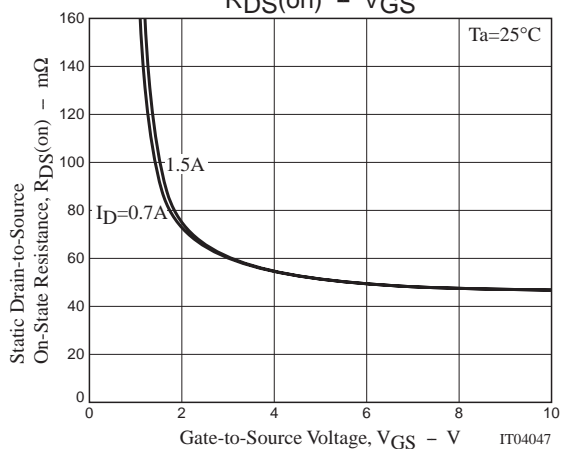
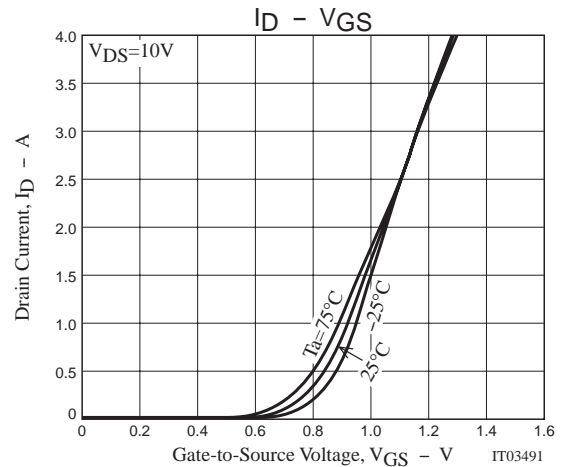
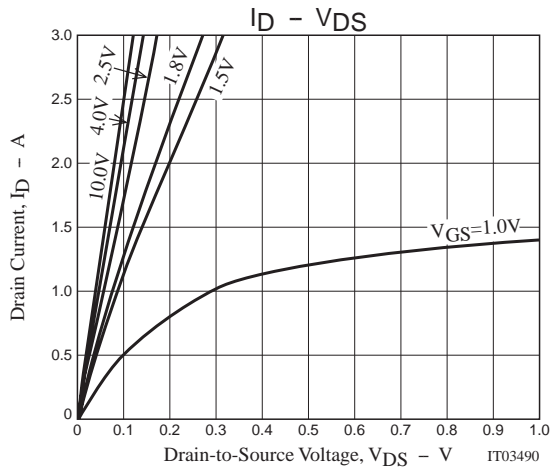
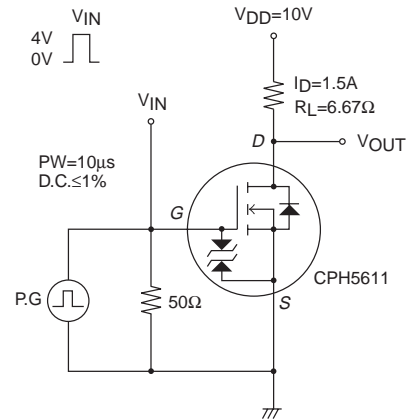
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		280		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		60		pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		38		pF
Turn-ON Delay Time	t _{d(on)}	See specified Test Circuit.		13		ns
Rise Time	t _r	See specified Test Circuit.		35		ns
Turn-OFF Delay Time	t _{d(off)}	See specified Test Circuit.		35		ns
Fall Time	t _f	See specified Test Circuit.		25		ns
Total Gate Charge	Q _g	V _{DS} =10V, V _{GS} =4V, I _D =3A		8.8		nC
Gate-to-Source Charge	Q _{gs}	V _{DS} =10V, V _{GS} =4V, I _D =3A		0.85		nC
Gate-to-Drain "Miller" Charge	Q _{gd}	V _{DS} =10V, V _{GS} =4V, I _D =3A		0.85		nC
Diode Forward Voltage	V _{SD}	I _S =3A, V _{GS} =0		0.84	1.2	V

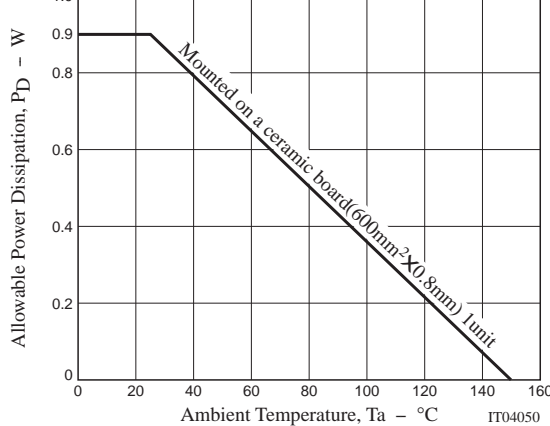
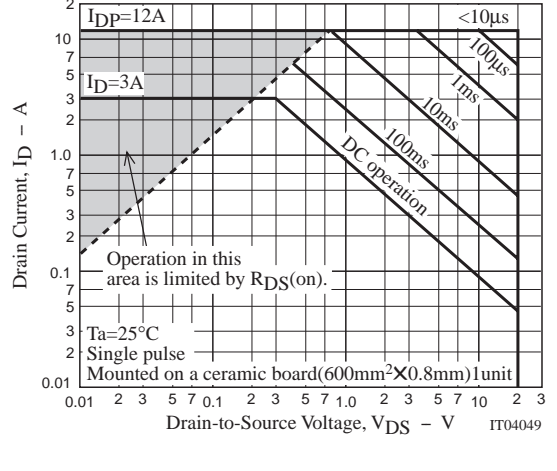
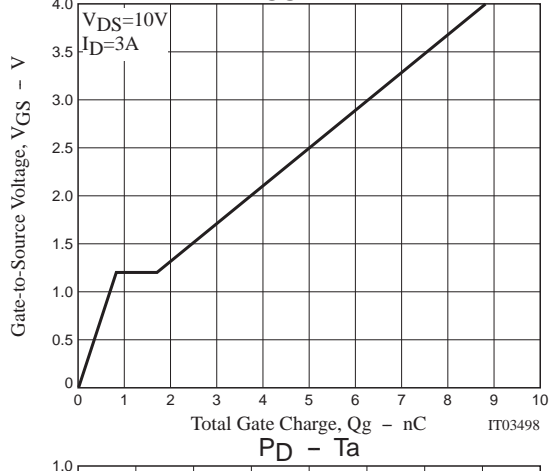
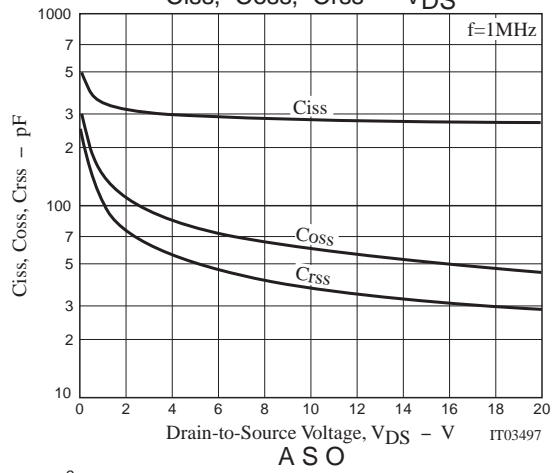
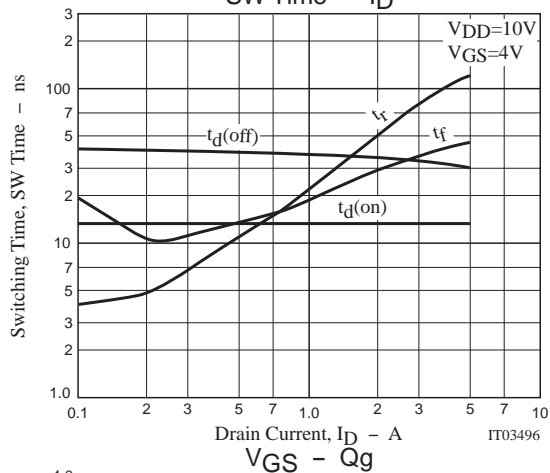
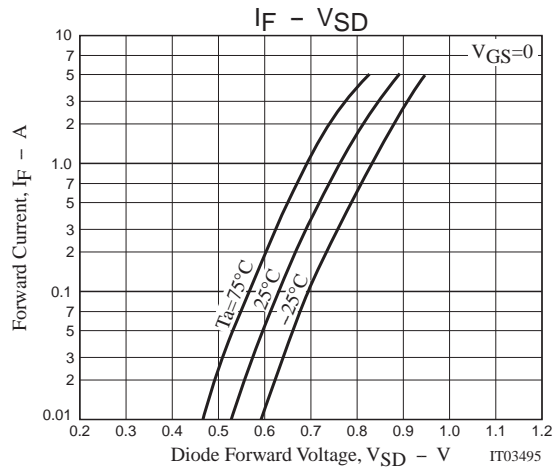
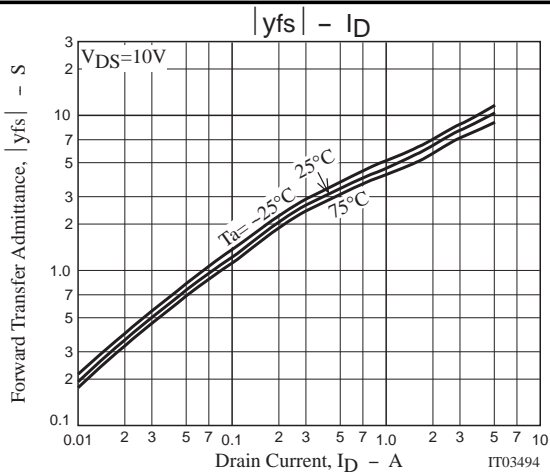
Electrical Connection



- 1 : Drain1
- 2 : Drain2
- 3 : Gate2
- 4 : Source
- 5 : Gate1

Switching Time Test Circuit





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